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FAIRCHILD

SEMICONDUCTOR

74F64 4-2-3-2-Input AND-OR-Invert Gate

General Description

This device contains gates configured to perform a 4-2-3-2 input AND-OR-INVERT function.

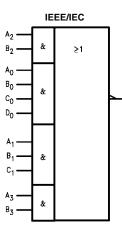
Ordering Code:

Order Number Package Number Package Description		
74F64SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
74F64SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F64PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

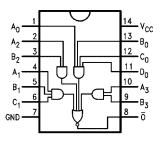
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

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Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}	
A _n , B _n , C _n , D _n	Inputs	1.0/1.0	20 µA/–0.6 mA	
ō	Output	50/33.3	–1 mA/20 mA	

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74F64

Absolute Maximum Ratings(Note 1)

Storage Temperature	-65°C to +150°C			
Ambient Temperature under Bias	-55°C to +125°C			
Junction Temperature under Bias	-55°C to +150°C			
V _{CC} Pin Potential to Ground Pin	-0.5V to +7.0V			
Input Voltage (Note 2)	-0.5V to +7.0V			
Input Current (Note 2)	-30 mA to +5.0 mA			
Voltage Applied to Output				
in HIGH State (with $V_{CC} = 0V$)				
Standard Output	–0.5V to V _{CC}			
3-STATE Output	-0.5V to +5.5V			
Current Applied to Output				
in LOW State (Max)	twice the rated I _{OL} (mA)			

Recommended Operating Conditions

Free Air Ambient Temperature Supply Voltage 0° C to +70°C +4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

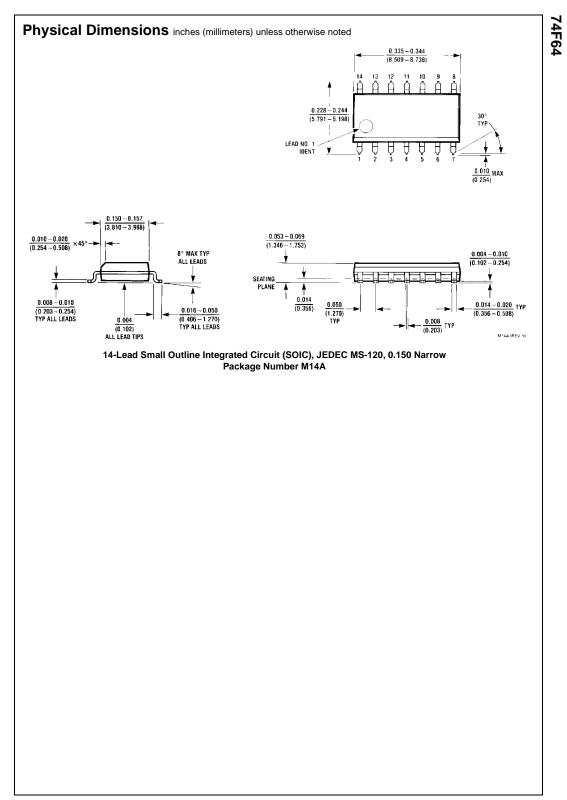
DC Electrical Characteristics

Symbol	ol Parameter		Units	V _{CC}	Conditions		
VIH	Input HIGH Voltage		V		Recognized as a HIGH Signal		
V _{IL}	Input LOW Voltage		V		Recognized as a LOW Signal		
V _{CD}	Input Clamp Diode Voltage		V	Min	I _{IN} = -18 mA		
V _{OH}	Output HIGH	10% V _{CC}	V	Min	$I_{OH} = -1 \text{ mA}$		
	Voltage	5% V _{CC}			$I_{OH} = -1 \text{ mA}$		
V _{OL}	Output LOW Voltage	10% V _{CC}	V	Min	I _{OL} = 20 mA		
I _{IH}	Input HIGH		۵	Max	V - 2.7V		
	Current		μΑ	ivlax	$V_{IN} = 2.7V$		
I _{BVI}	Input HIGH Current			Maria)/ 70)/		
	Breakdown Test		μA Max		V _{IN} = 7.0V		
ICEX	Output High Leakage Current		μA	Max	$V_{OUT} = V_{CC}$		
V _{ID}	Input Leakage		V	0.0	I _{ID} = 1.9 μA		
	Test		v 0.0		All Other Pins Grounded		
I _{OD}	Output Leakage	utput Leakage		0.0	$V_{IOD} = 150 \text{ mV}$		
	Circuit Current		μΑ	0.0	All Other Pins Grounded		
IIL	Input LOW Current		mA	Max	$V_{IN} = 0.5V$		
I _{OS}	Output Short-Circuit Current		mA	Max	$V_{OUT} = 0V$		
ICCH	Power Supply Current		mA	Max	V _O = HIGH		
I _{CCL}	Power Supply Current		mA	Max	$V_0 = LOW$		

AC Electrical Characteristics

Symbol	Parameter	T _A = +25°C V _{CC} = +5.0V C _L = 50 pF			T _A = 0° to +70°C C _L = 50 pF		Units
		Min	Тур	Max	Min	Max	
t _{PLH}	Propagation Delay	2.5	4.6	6.5	2.5	7.5	ns
t _{PHL}	$A_n, B_n, C_n, D_n \text{ to } \overline{O}$	1.5	3.2	4.5	1.5	5.5	115

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